

L Number	Hits	Search Text	DB	Time stamp
-	163	low near3 temperature near10 (si or silicon) near4 (deposit\$5 or growth) near10 (monocrystal\$4 or monocrystallin\$5 or single near4 crystal\$)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/10/08 16:26
-	36	(low near3 temperature near10 (si or silicon) near4 (deposit\$5 or growth) near10 (monocrystal\$4 or monocrystallin\$5 or single near4 crystal\$)) and 117\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/10/08 16:26